## NSN 5961-01-485-9554

A110a0

Semiconductor Device Set - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-485-9554

view Offilite at https://aerobasegroup.com/hist//0301-01-400-3004
Inclosure Material:
Plastic all semiconductor device diode
Overall Length:
4.500 inches all semiconductor device diode
End Application:
5895-01-479-9735
Component Function Relationship:
Matched
Component Name And Quantity:
2 semiconductor device diode
Mounting Method:
Terminal all semiconductor device diode
Semiconductor Material:
Silicon all semiconductor device diode
Voltage Rating In Volts Per Characteristic:
171.00 breakdown voltage, dc all semiconductor device diode and 189.00 breakdown voltage, dc all semiconductor device diode and
150.00 working peak reverse voltage all semiconductor device diode
Current Rating Per Characteristic:
5.00 microamperes forward current, average peak all semiconductor device diode
Special Features:
Contains 2ea jantx1n6069a diodes
Terminal Type And Quantity:
2 quick disconnect, female all semiconductor device diode and 1 insulated wire lead w/terminal lug all semiconductor device diode
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiia: